

10Mbit/s High Speed Logic Gate Photo Coupler

Description

The SLM601 series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon high speed integrated photo-detector logic gate with a strobeable output in a plastic SOP5 package.

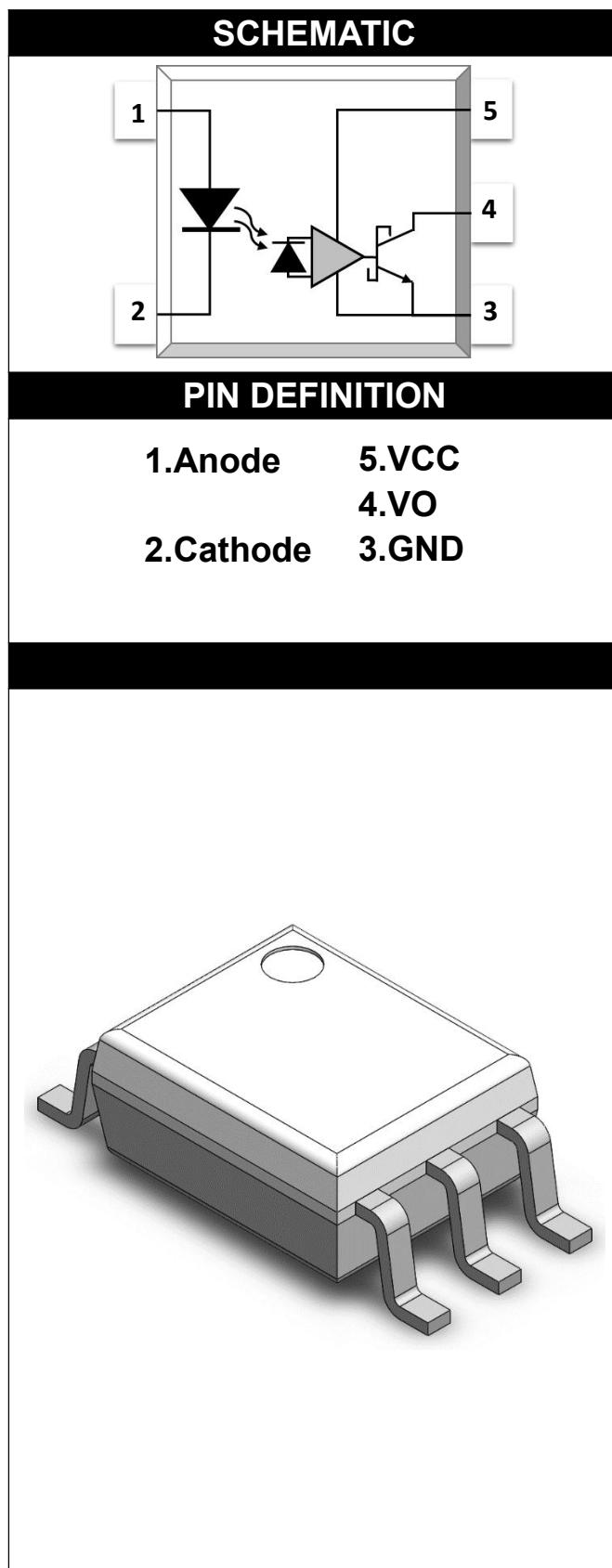
With the robust coplanar double mold structure, SLM601 series provide the most stable isolation feature.

Features

- High isolation 3750 VRMS
- DC input with logic gate output
- Operating temperature range - 55 °C to 100 °C
- REACH compliance
- Halogen free
- MSL class 1
- Regulatory Approvals
 - UL - UL1577
 - VDE - EN60747-5-5(VDE0884-5)
 - CQC - GB4943.1, GB8898
 - cUL- CSA Component Acceptance Service Notice No. 5A

Applications

- Ground loop elimination
- LSTTL to TTL, LSTTL or CMOS
- Line receiver, data transmission
- Data multiplexing
- Switching power supply
- Pulse transformer replacement



ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	VALUE	UNIT	Note
INPUT				
Forward Current	I _F	25	mA	
Peak Forward Current	I _{FP}	50	mA	1
Peak Transient Current	I _{F(trans)}	1	A	2
Reverse Voltage	V _R	5	V	
Enable Voltage	V _E	VCC+0.5	V	
Input Power Dissipation	P _I	100	mW	
OUTPUT				
Supply Voltage	V _{CC}	7	V	
Output Voltage	V _O	7	V	
Output Current	I _O	50	mA	
Output Power Dissipation	P _O	85	mW	
COMMON				
Total Power Dissipation	P _{tot}	200	mW	
Isolation Voltage	V _{iso}	3750	Vrms	3
Operating Temperature	T _{opr}	-55~100	°C	
Storage Temperature	T _{stg}	-55~125	°C	
Soldering Temperature	T _{sol}	260	°C	4

Note 1. 50% duty, 1ms P.W

Note 2. $\leq 1\mu s$ P.W,300pps

Note 3. AC For 1 Minute, R.H. = 40 ~ 60%

Note 4. For 10 seconds

RECOMMENDED OPERATION CONDITIONS				
PARAMETER	SYMBOL	MIN.	MAX.	UNIT
Operating Temperature	TA	-40	100	°C
Supply Voltage	VCC	2.7	3.6	V
	VCC	4.5	5.5	V
Low Level Input Current	IFL	0	250	µA
High Level Input Current	IFH	5	15	mA
Low Level Enable Voltage	VEL	0	0.8	V
High Level Enable Voltage	VEH	2	VCC	V
Output Pull-up Resistor	RL	330	4k	Ω
Fan Out (at RL=1kΩ per channel)	N	-	5	TTL Loads

ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C							
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
INPUT							
Forward Voltage	V _F	-	1.38	1.8	V	I _F =10mA	
Reverse Current	I _R	-	-	10	µA	V _R =5V	
Input Capacitance	C _{in}	-	13	-	pF	V=0, f=1MHz	
OUTPUT							
High Level Supply Current	I _{CCH}	-	6.3	10	mA	I _F =0mA, V _E =0.5V, V _{CC} =5.5V	
Low Level Supply Current	I _{CCL}	-	8.3	13	mA	I _F =10mA, V _{CC} =5.5V	
TRANSFER CHARACTERISTICS (Ta=-40 to 85°C)							
High Level Output Current	I _{OH}	-	0.73	100	µA	V _{CC} =5.5V, V _O =5.5V, I _F =250µA, V _E =2.0V	
Low Level Output Voltage	V _{OL}	-	0.28	0.6	V	V _{CC} =5.5V, I _F =5mA, V _E =2.0V, I _{OL} =13mA	
Input Threshold Current	I _{FT}	-	2.5	5	mA	V _{CC} =5.5V, V _O =0.6V, V _E =2.0V, I _{OL} =13mA	
Isolation Resistance	R _{iso}	10 ¹²	10 ¹⁴	-	Ω	DC500V, 40 ~ 60% R.H.	
Floating Capacitance	C _{IO}	-	1.0	-	pF	V=0, f=1MHz	

ELECTRICAL OPTICAL CHARACTERISTICS

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
SWITCHING CHARACTERISTICS (Ta=-40 to 85°C, V _{CC} =5V, I _F =7.5mA unless specified otherwise)							
Propagation Delay Time to Output Low Level	TPHL	-	35	75	ns	C _L =15pF, R _L =350Ω, Ta=25°C	Fig.23
Propagation Delay Time to Output High Level	TPLH	-	40	75	ns	C _L =15pF, R _L =350Ω, Ta=25°C	Fig.23
Pulse Width Distortion	TPHL-TPLH	-	5	35	ns	C _L =15pF, R _L =350Ω	Fig.23
Rise Time	tr	-	27	-	ns	C _L =15pF, R _L =350Ω	Fig.23
Fall Time	tf	-	7	-	ns	C _L =15pF, R _L =350Ω	Fig.23
Common Mode Transient Immunity at Logic High	CMH	10000	-	-	V/μs	I _F = 7.5mA , V _{OH} =2.0V, R _L =350Ω, Ta=25°C V _{CM} =400Vp-p	Fig.24
Common Mode Transient Immunity at Logic Low	CML	10000	-	-	V/μs	I _F = 0mA , V _{OH} =0.8V, R _L =350Ω, Ta=25°C V _{CM} =400Vp-p	Fig.24

ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C

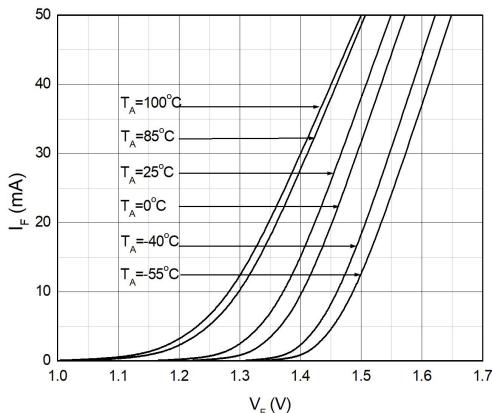
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
INPUT							
Forward Voltage	V _F	-	1.38	1.8	V	I _F =10mA	
Reverse Current	I _R	-	-	10	µA	V _R =5V	
Input Capacitance	C _{in}	-	13	-	pF	V=0, f=1MHz	
OUTPUT							
High Level Supply Current	I _{CCH}	-	4.3	10	mA	I _F =0mA, V _E =0.5V, V _{CC} =3.3V	
Low Level Supply Current	I _{CCL}	-	6.4	13	mA	I _F =10mA, V _{CC} =3.3V	
TRANSFER CHARACTERISTICS (Ta=-40 to 85°C)							
High Level Output Current	I _{OH}	-	4.1	100	µA	V _{CC} =3.3V, V _O =3.3V, I _F =250µA, V _E =2.0V	
Low Level Output Voltage	V _{OL}	-	0.29	0.6	V	V _{CC} =3.3V, I _F =5mA, V _E =2.0V, I _{OL} =13mA	
Input Threshold Current	I _{FT}	-	2.2	5	mA	V _{CC} =3.3V, V _O =0.6V, V _E =2.0V, I _{OL} =13mA	
Isolation Resistance	R _{iso}	10 ¹²	10 ¹⁴	-	Ω	DC500V, 40 ~ 60% R.H.	
Floating Capacitance	C _{IO}	-	1.0	-	pF	V=0, f=1MHz	

ELECTRICAL OPTICAL CHARACTERISTICS

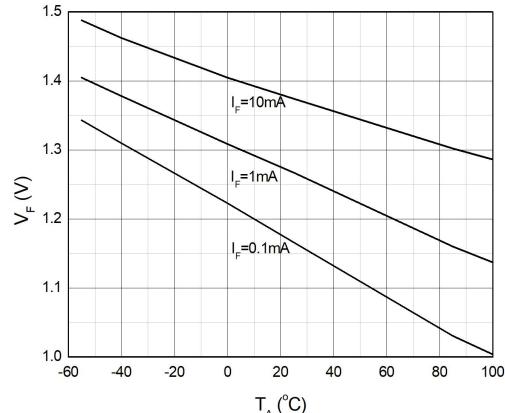
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
SWITCHING CHARACTERISTICS ($T_a = -40$ to $85^\circ C$, $V_{CC} = 3.3V$, $I_F = 7.5mA$ unless specified otherwise)							
Propagation Delay Time to Output Low Level	TPHL	-	35	75	ns	$C_L = 15pF$, $R_L = 350\Omega$, $T_a = 25^\circ C$	Fig.23
Propagation Delay Time to Output High Level	TPLH	-	47	75	ns	$C_L = 15pF$, $R_L = 350\Omega$, $T_a = 25^\circ C$	Fig.23
Pulse Width Distortion	$ TPHL-TPLH $	-	12	35	ns	$C_L = 15pF$, $R_L = 350\Omega$	Fig.23
Rise Time	tr	-	30	-	ns	$C_L = 15pF$, $R_L = 350\Omega$	Fig.23
Fall Time	tf	-	8.5	-	ns	$C_L = 15pF$, $R_L = 350\Omega$	Fig.23
Common Mode Transient Immunity at Logic High	CMH	10000	-	-	V/ μ s	$I_F = 7.5mA$, $V_{OH} = 2.0V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 400Vp-p$	Fig.24
Common Mode Transient Immunity at Logic Low	CML	10000	-	-	V/ μ s	$I_F = 0mA$, $V_{OH} = 0.8V$, $R_L = 350\Omega$, $T_a = 25^\circ C$ $V_{CM} = 400Vp-p$	Fig.24

CHARACTERISTIC CURVES

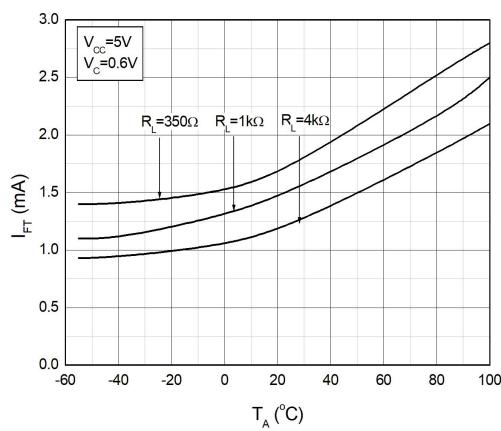
**Fig.1 Forward Current
vs. Forward Voltage**



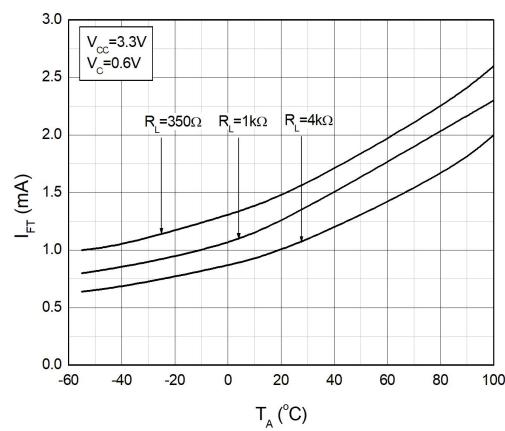
**Fig.2 Forward Voltage
vs. Ambient Temperature**



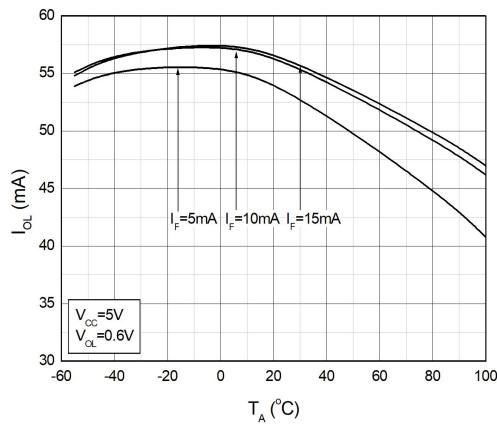
**Fig.3 Input Threshold Current
vs. Ambient Temperature**



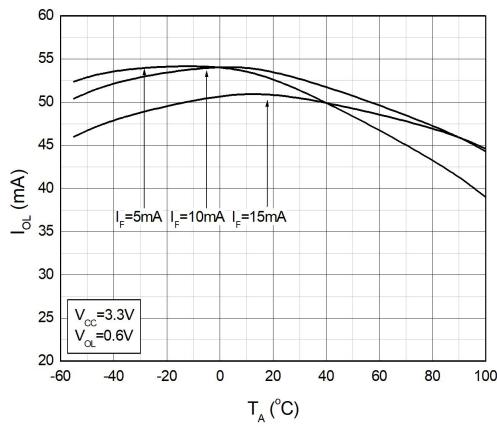
**Fig.4 Input Threshold Current
vs. Ambient Temperature**



**Fig.5 Low Level Output Current
vs. Ambient Temperature**



**Fig.6 Low Level Output Current
vs. Ambient Temperature**



CHARACTERISTIC CURVES

Fig.7 Low Level Output Voltage vs. Ambient Temperature

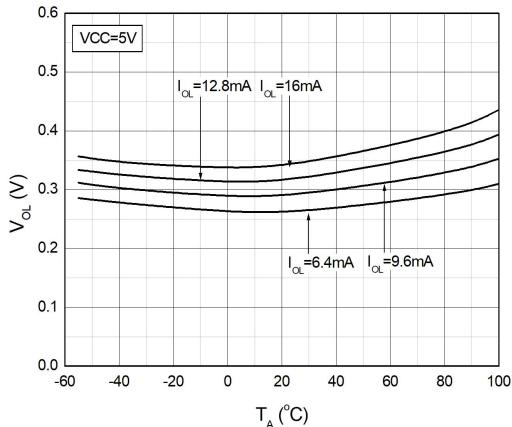


Fig.8 Low Level Output Voltage vs. Ambient Temperature

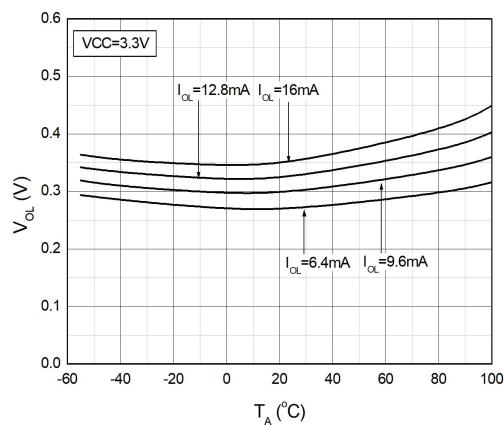


Fig.9 High Level Output Current vs. Ambient Temperature

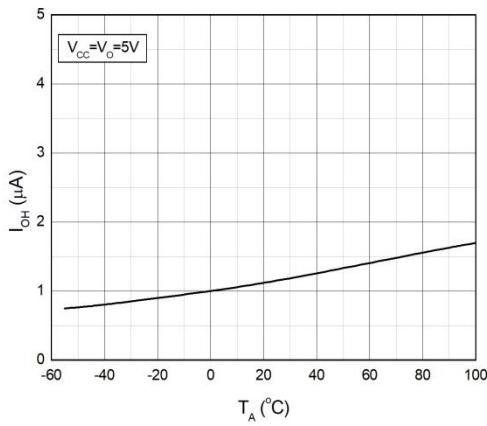


Fig.10 High Level Output Current vs. Ambient Temperature

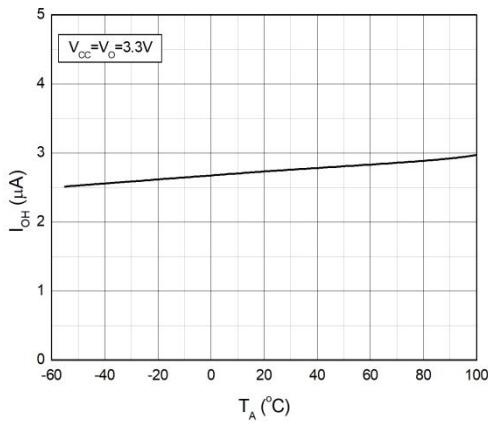


Fig.11 Output Voltage vs. Forward Current

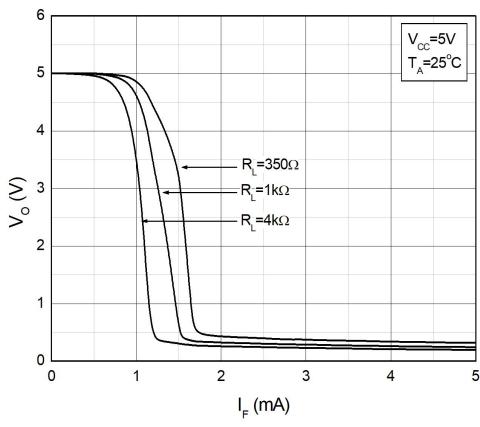
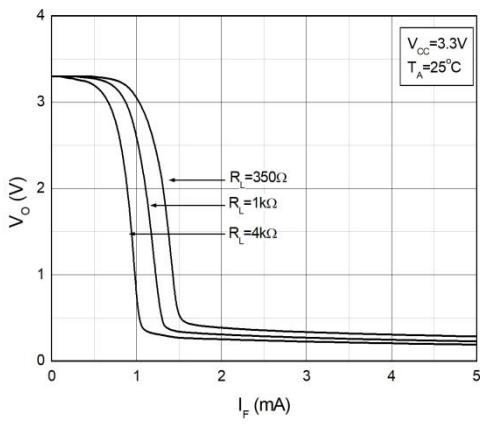
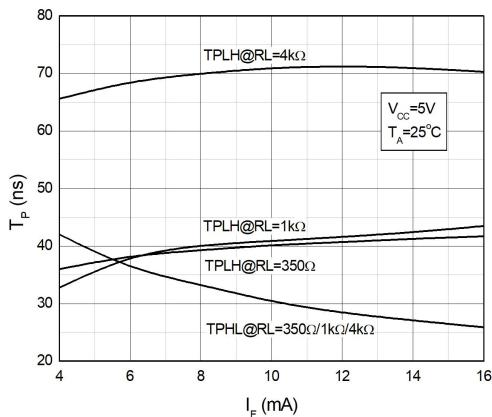


Fig.12 Output Voltage vs. Forward Current

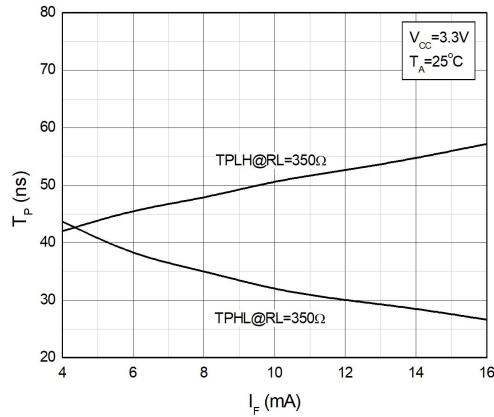


CHARACTERISTIC CURVES

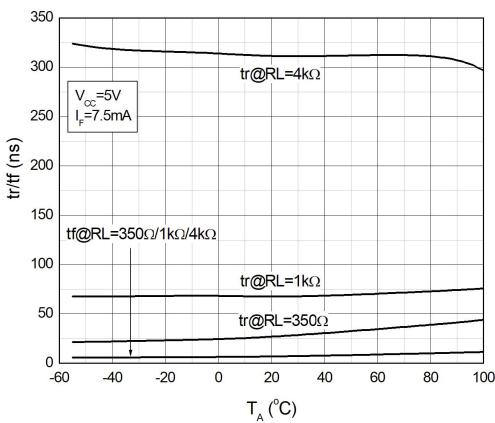
**Fig.13 Propagation Delay
vs. Forward Current**



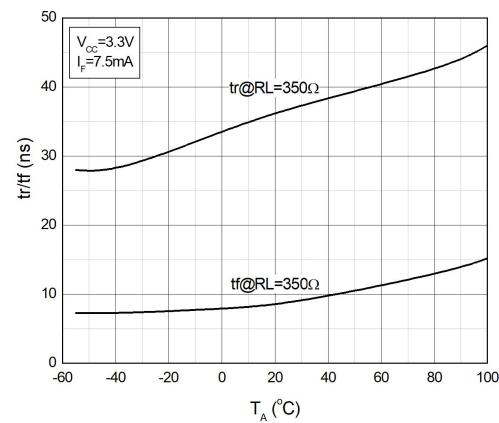
**Fig.14 Propagation Delay
vs. Forward Current**



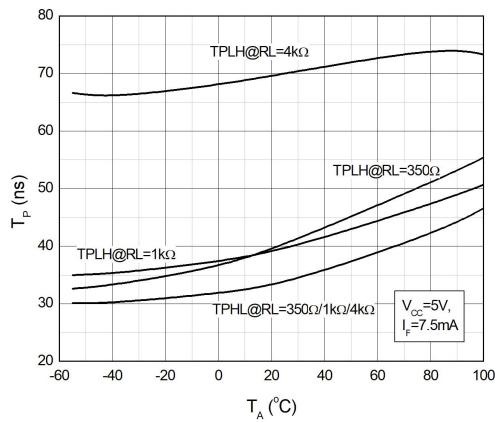
**Fig.15 Rise and Fall Time
vs. Ambient Temperature**



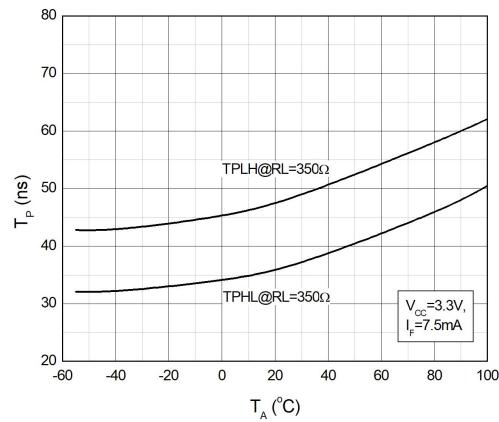
**Fig.16 Rise and Fall Time
vs. Ambient Temperature**

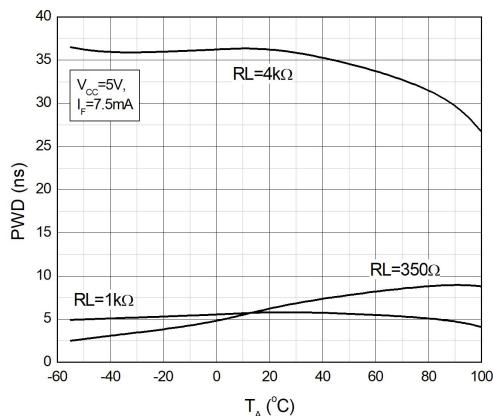
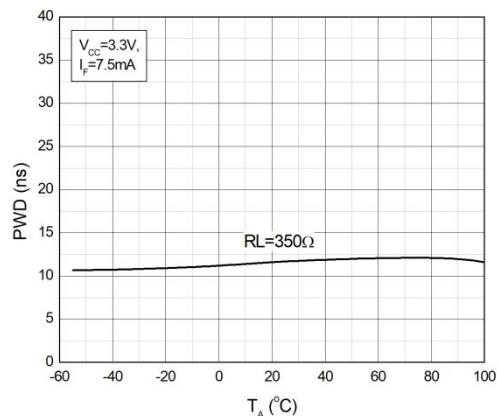


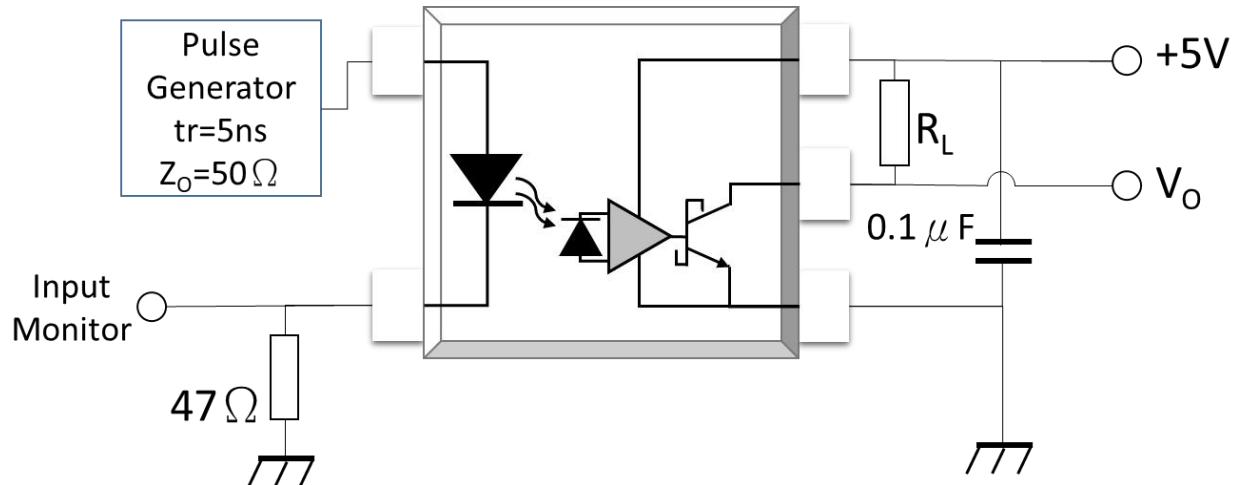
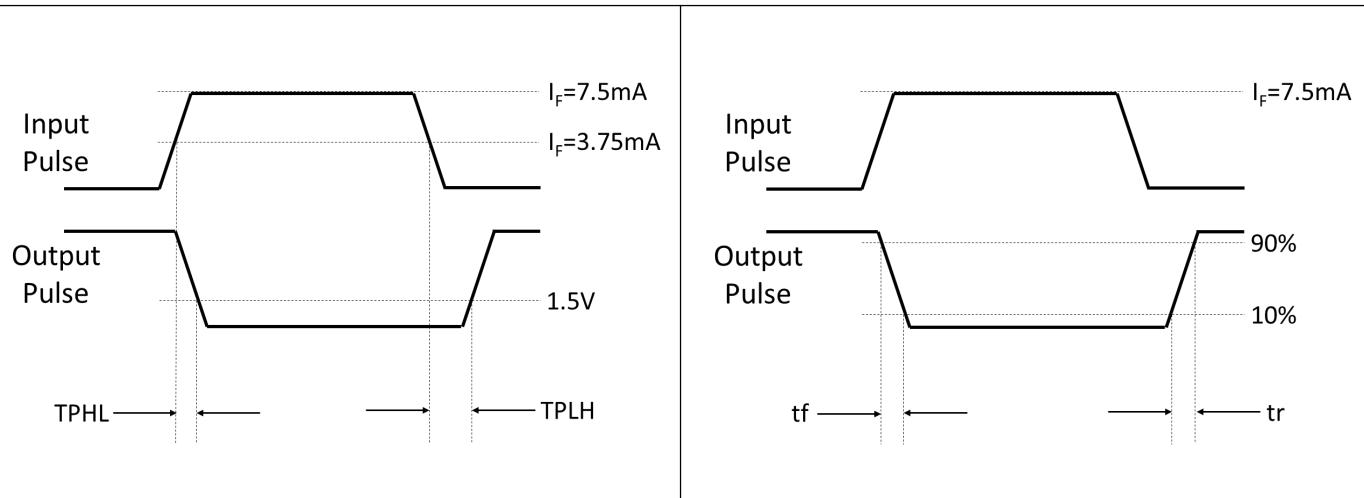
**Fig.17 Propagation Delay
vs. Ambient Temperature**

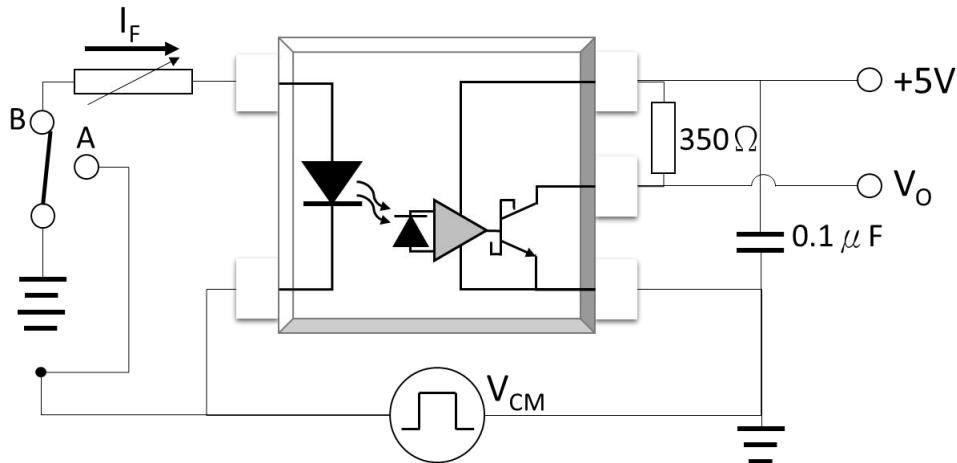
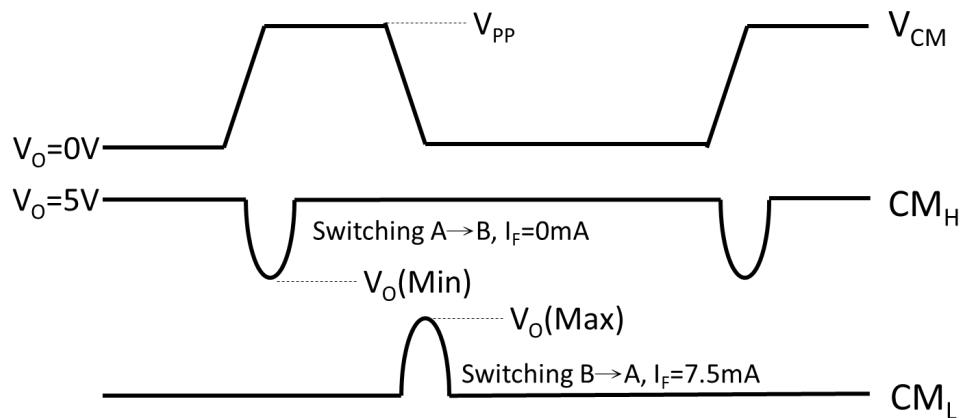


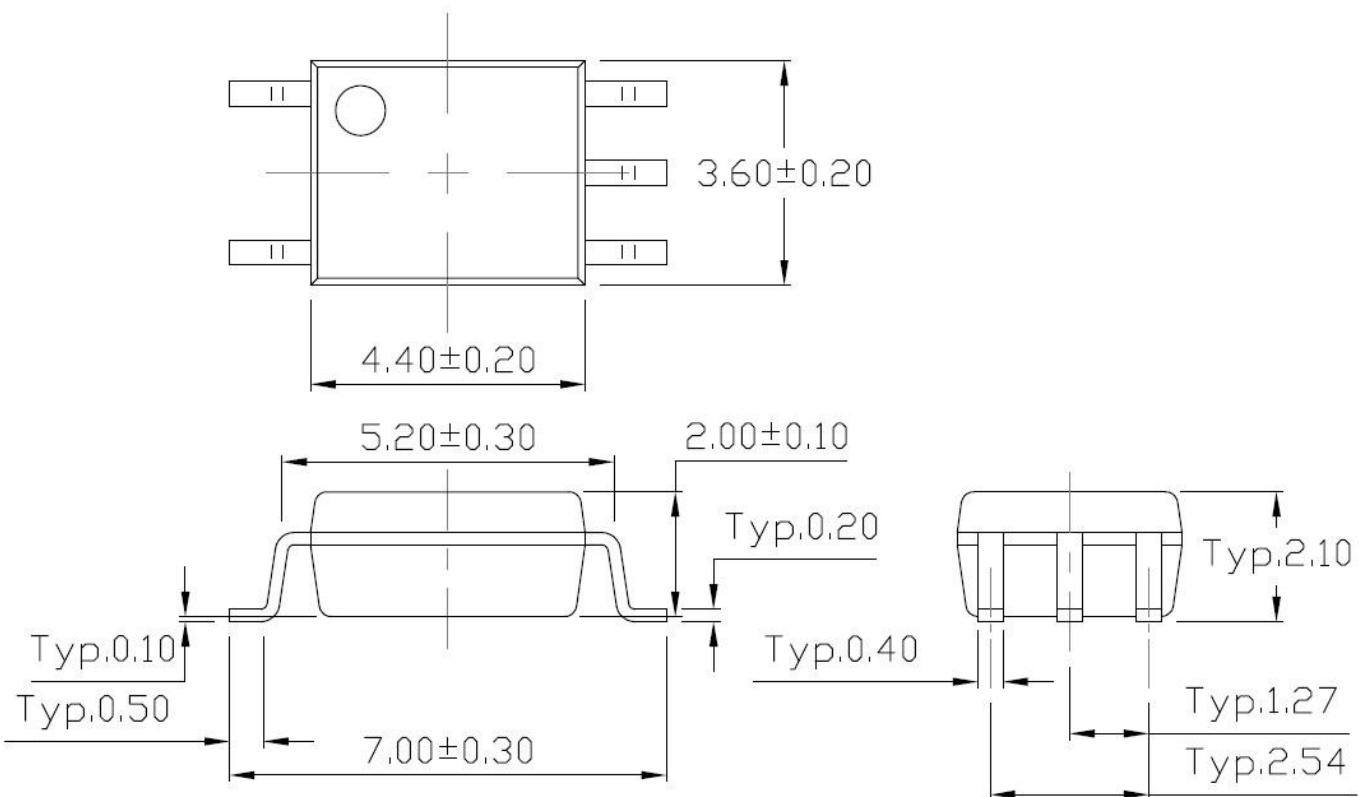
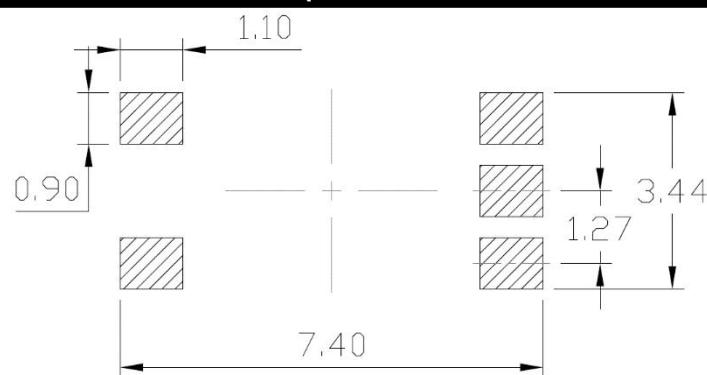
**Fig.18 Propagation Delay
vs. Ambient Temperature**

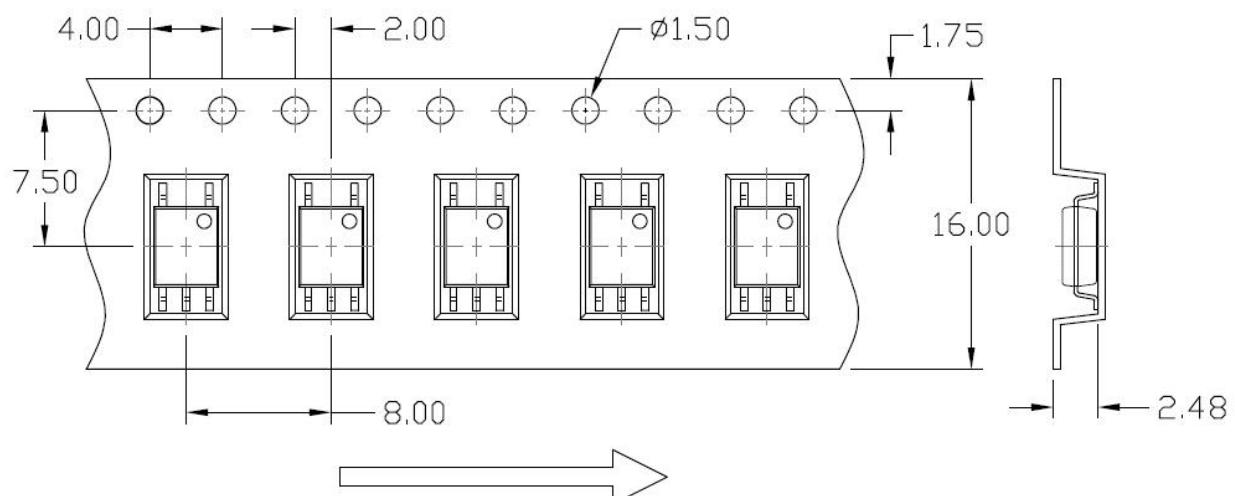
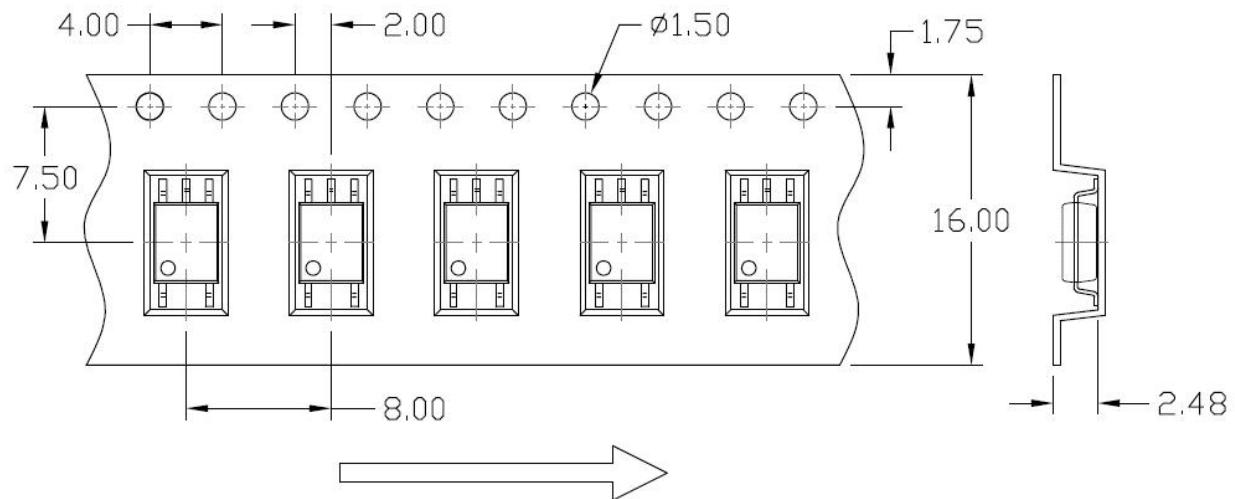


CHARACTERISTIC CURVES**Fig.19 Pulse Width Distortion
vs. Ambient Temperature****Fig.20 Pulse Width Distortion
vs. Ambient Temperature**

TEST CIRCUITS**Fig.23 Test Circuits for TPHL, TPLH, tr, tf****Fig.24 Waveforms of TPHL, TPLH, tr, tf**

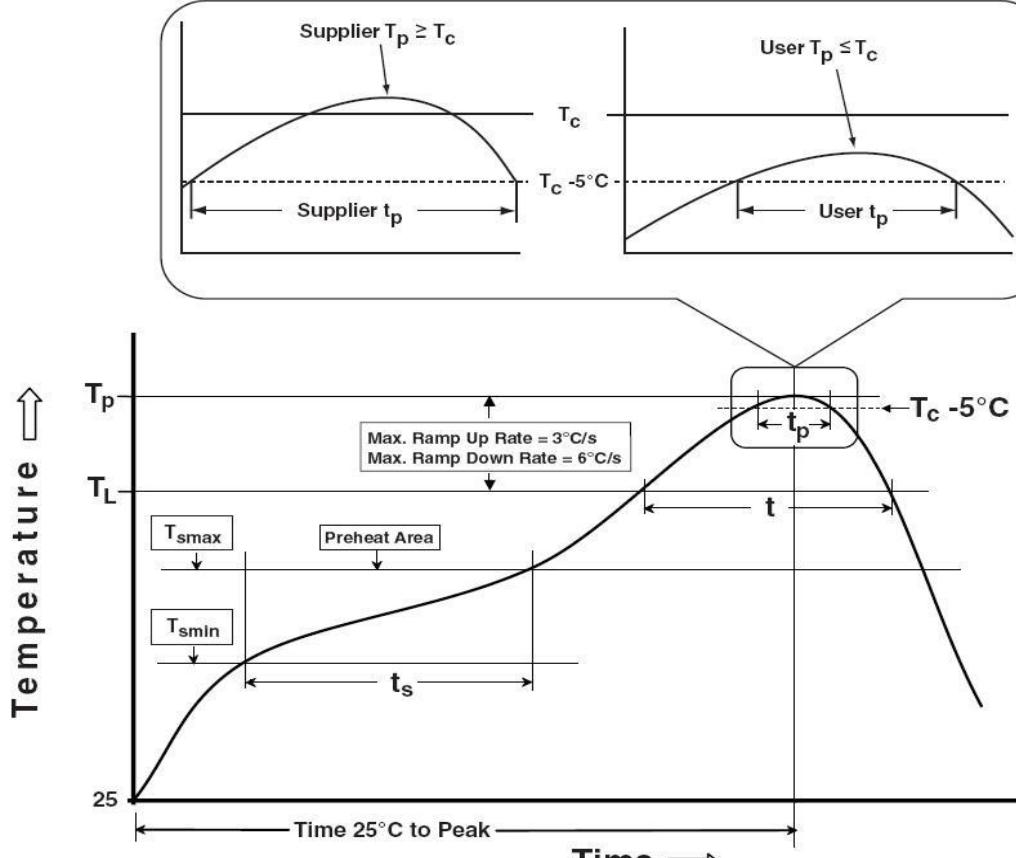
TEST CIRCUITS**Fig.24 Test Circuits for Common Mode Transient Immunity****Fig.26 Waveforms of Common Mode Transient Immunity**

PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)**Recommended Solder Mask** (Dimensions in mm unless otherwise stated)

CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)**Option T1****Option T2**

REFLOW INFORMATION

REFLOW PROFILE



IPC-020d-5-1

Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T_{smin})	100	150°C
Temperature Max. (T_{smax})	150	200°C
Time (t_s) from (T_{smin} to T_{smax})	60-120 seconds	60-120 seconds
Ramp-up Rate (t_L to t_p)	3°C/second max.	3°C/second max.
Liquidous Temperature (T_L)	183°C	217°C
Time (t_L) Maintained Above (T_L)	60 – 150 seconds	60 – 150 seconds
Peak Body Package Temperature	235°C +0°C / -5°C	260°C +0°C / -5°C
Time (t_p) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T_p to T_L)	6°C/second max	6°C/second max
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

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[TLP5772H\(D4LF4,E\)](#) [TLP5774H\(LF4,E\)](#) [TLP5771H\(D4LF4,E\)](#) [TLP5771H\(LF4,E\)](#) [TLP5774H\(E\)](#) [TLP5214A\(E\(O](#) [LTV-5341-TP1](#) [OR-314W-](#)
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[ACPL-W343-500E](#) [TLP351H\(TP1,F\)](#) [TLP352](#) [FOD3120SDV](#) [FOD3184TSR2V](#) [6N140A](#) [6N140A#300](#) [HCPL-0466-500E](#)